

Chapter 4: Imperfections in Solids

- What are the solidification mechanisms?
- What types of defects arise in solids?
- Can the number and type of defects be varied and controlled?
- How do defects affect material properties?
- Are defects undesirable?



Imperfections in Solids

There is no such thing as a perfect crystal.

- What are these imperfections?
- Why are they important?

Many of the important properties of materials are due to the presence of imperfections.



Types of Imperfections

- Vacancy atoms
- Interstitial atoms
- Substitutional atoms

Point defects

- Dislocations

Line defects

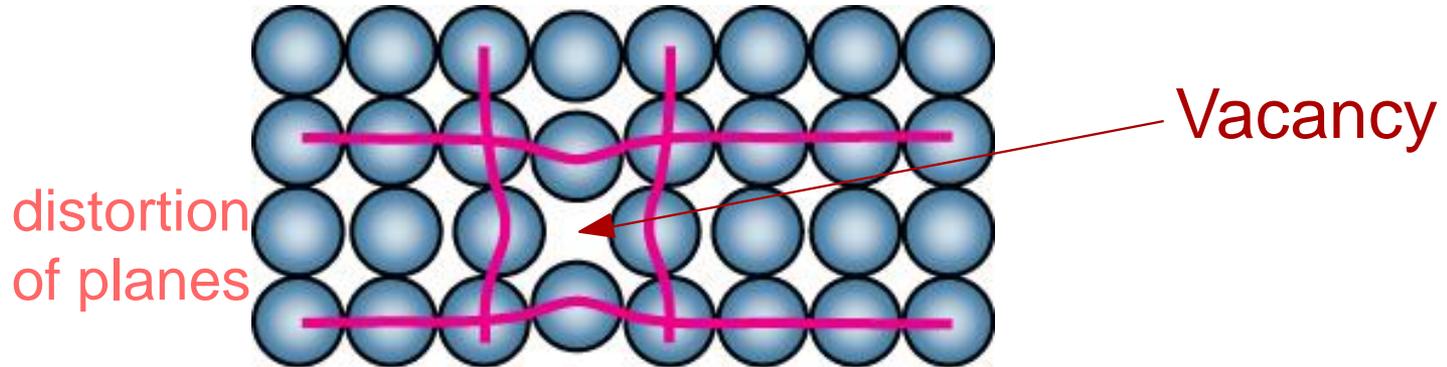
- Grain Boundaries

Planar defects

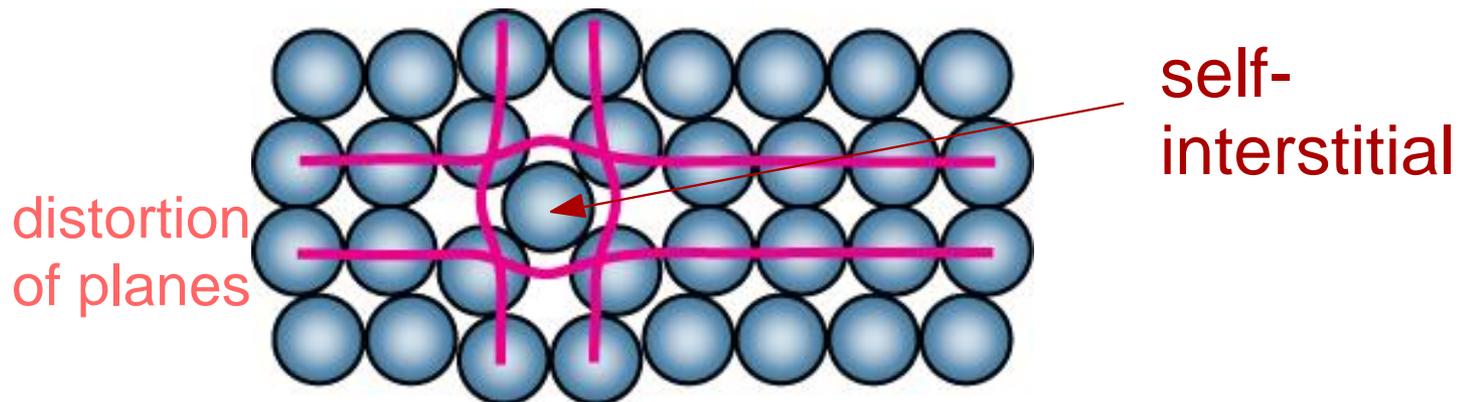


Point Defects in Metals

- **Vacancies:**
-vacant atomic sites in a structure.



- **Self-Interstitials:**
-"extra" atoms positioned between atomic sites.



Equilibrium Concentration: Point Defects

- Equilibrium concentration varies with temperature!

No. of defects $\rightarrow N_v$

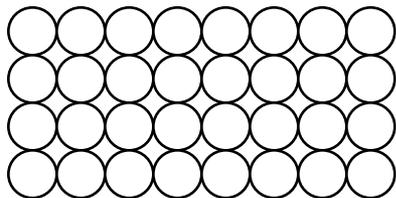
No. of potential defect sites $\rightarrow N$

$$\frac{N_v}{N} = \exp\left(\frac{-Q_v}{kT}\right)$$

Activation energy $\rightarrow Q_v$

Boltzmann's constant $\rightarrow k$

Temperature $\rightarrow T$



Each lattice site
is a potential
vacancy site

$(1.38 \times 10^{-23} \text{ J/atom-K})$
 $(8.62 \times 10^{-5} \text{ eV/atom-K})$



Estimating Vacancy Concentration

- Find the equil. # of vacancies in 1 m³ of Cu at 1000°C.
- Given:

$$\rho = 8.4 \text{ g/cm}^3 \quad A_{\text{Cu}} = 63.5 \text{ g/mol}$$

$$Q_V = 0.9 \text{ eV/atom} \quad N_A = 6.02 \times 10^{23} \text{ atoms/mol}$$

$$\frac{N_V}{N} = \exp\left(\frac{-Q_V}{kT}\right) = 2.7 \times 10^{-4}$$

↖ 0.9 eV/atom
↙ 1273 K
↘ 8.62 × 10⁻⁵ eV/atom-K

For 1 m³, $N = \rho \times \frac{N_A}{A_{\text{Cu}}} \times 1 \text{ m}^3 = 8.0 \times 10^{28}$ sites

- Answer:

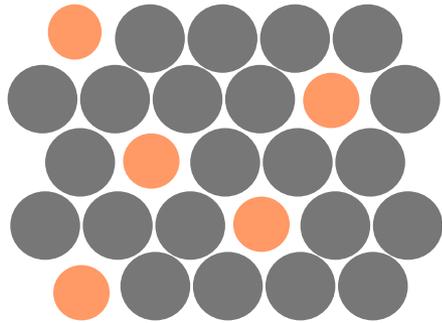
$$N_V = (2.7 \times 10^{-4})(8.0 \times 10^{28}) \text{ sites} = 2.2 \times 10^{25} \text{ vacancies}$$



Imperfections in Metals (i)

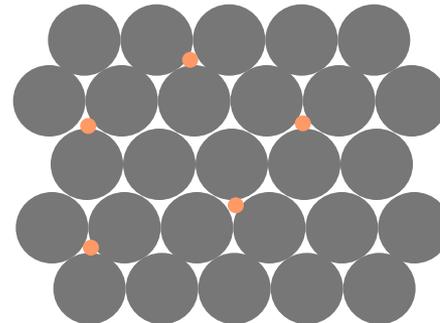
Two outcomes if impurity (B) added to host (A):

- **Solid solution** of B in A (i.e., random dist. of point defects)



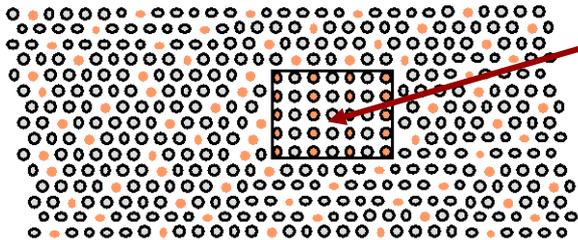
Substitutional solid soln.
(e.g., **Cu** in Ni)

OR



Interstitial solid soln.
(e.g., **C** in Fe)

- Solid solution of B in A plus particles of a new phase (usually for a larger amount of B)



Second phase particle
-- different **composition**
-- often different structure.

Imperfections in Metals (ii)

Conditions for substitutional solid solution (S.S.)

- **W. Hume – Rothery rule**

- 1. Δr (atomic radius) < 15%
- 2. Proximity in periodic table
 - i.e., similar electronegativities
- 3. Same crystal structure for pure metals
- 4. Valency
 - All else being equal, a metal will have a greater tendency to dissolve a metal of higher valency than one of lower valency



Imperfections in Metals (iii)

Application of Hume–Rothery rules – Solid Solutions

1. Would you predict more Al or Ag to dissolve in Zn?

2. More Zn or Al in Cu?

<i>Element</i>	<i>Atomic Radius (nm)</i>	<i>Crystal Structure</i>	<i>Electro-negativity</i>	<i>Valence</i>
Cu	0.1278	FCC	1.9	+2
C	0.071			
H	0.046			
O	0.060			
Ag	0.1445	FCC	1.9	+1
Al	0.1431	FCC	1.5	+3
Co	0.1253	HCP	1.8	+2
Cr	0.1249	BCC	1.6	+3
Fe	0.1241	BCC	1.8	+2
Ni	0.1246	FCC	1.8	+2
Pd	0.1376	FCC	2.2	+2
Zn	0.1332	HCP	1.6	+2

Table on p. 118, *Callister & Rethwisch 8e.*



Impurities in Solids

- Specification of composition

- weight percent $C_1 = \frac{m_1}{m_1 + m_2} \times 100$

m_1 = mass of component 1

- atom percent $C'_1 = \frac{n_{m1}}{n_{m1} + n_{m2}} \times 100$

n_{m1} = number of moles of component 1



Line Defects

Dislocations:

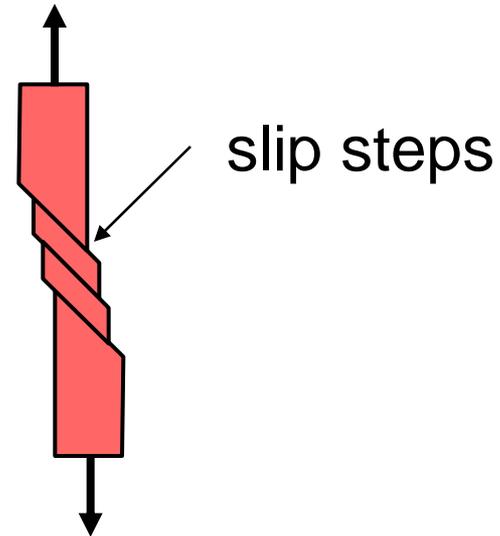
- are line defects,
- slip between crystal planes result when dislocations move,
- produce permanent (plastic) deformation.

Schematic of Zinc (HCP):

- before deformation



- after tensile elongation



Imperfections in Solids

Linear Defects (**Dislocations**)

- Are one-dimensional defects around which atoms are misaligned
- **Edge dislocation:**
 - extra half-plane of atoms inserted in a crystal structure
 - **b** perpendicular (\perp) to dislocation line
- **Screw dislocation:**
 - spiral planar ramp resulting from shear deformation
 - **b** parallel (\parallel) to dislocation line

Burger's vector, **b:** measure of lattice distortion



Imperfections in Solids

Edge Dislocation

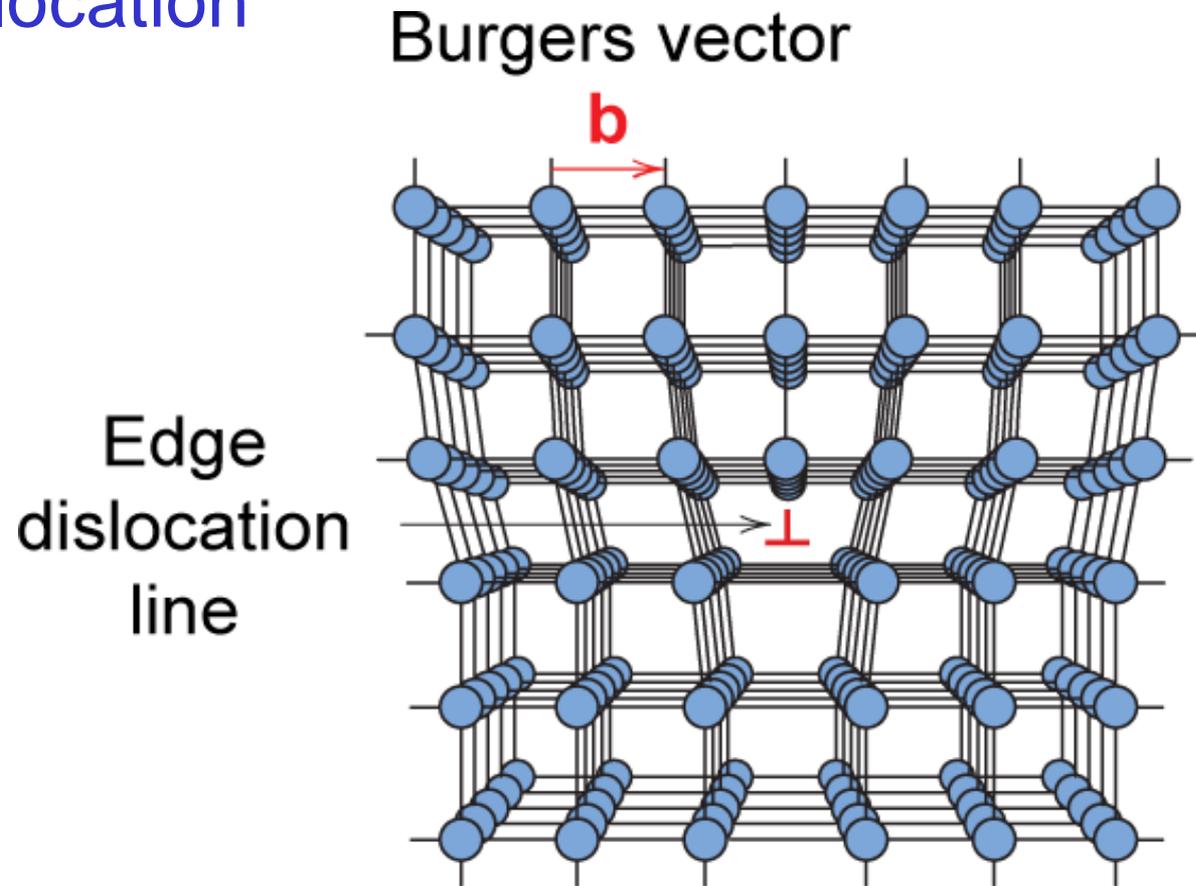
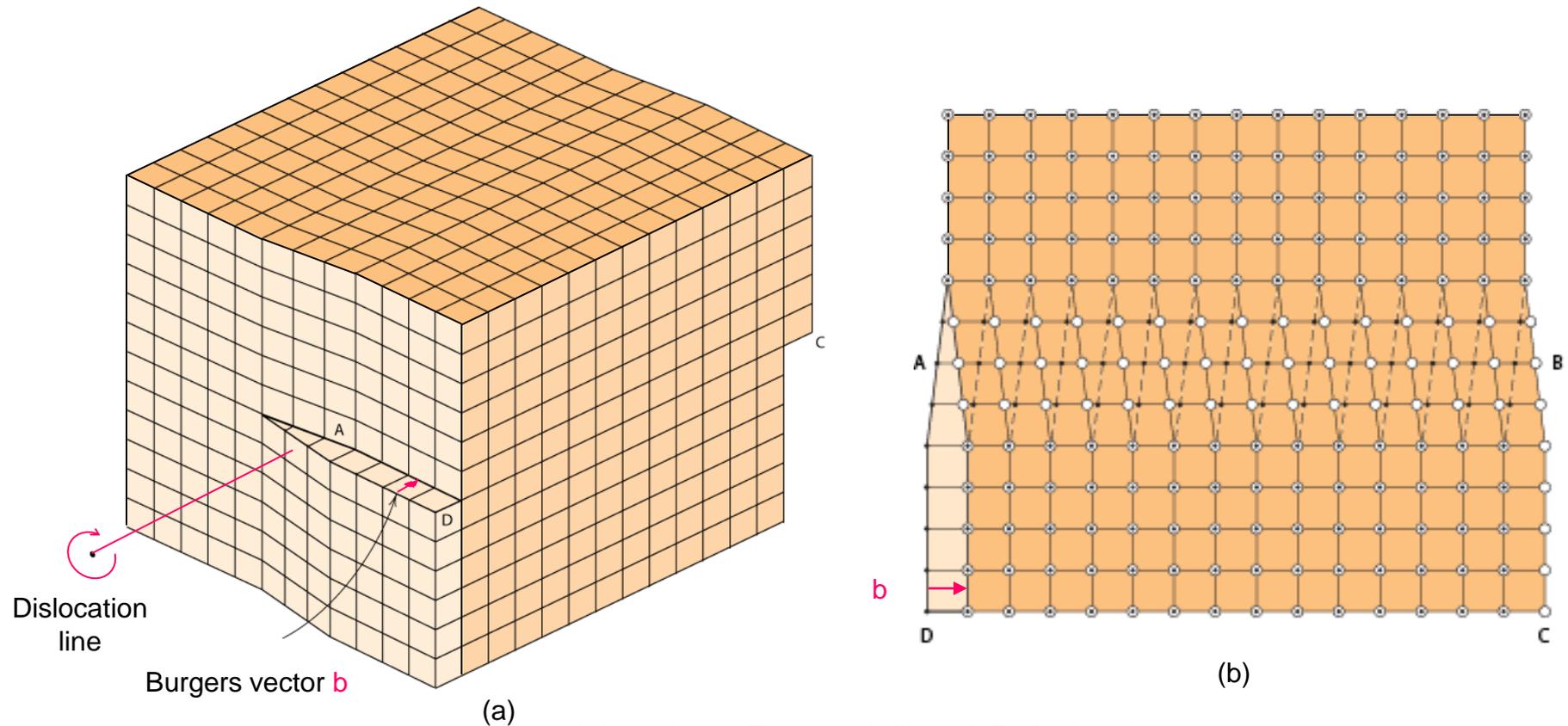


Fig. 4.3, Callister & Rethwisch 8e.

Imperfections in Solids

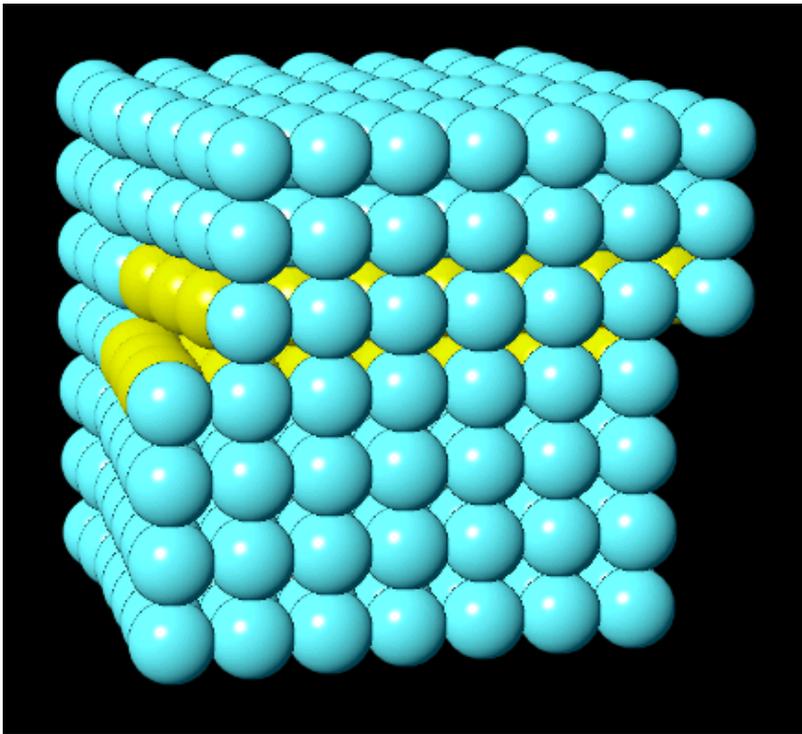
Screw Dislocation



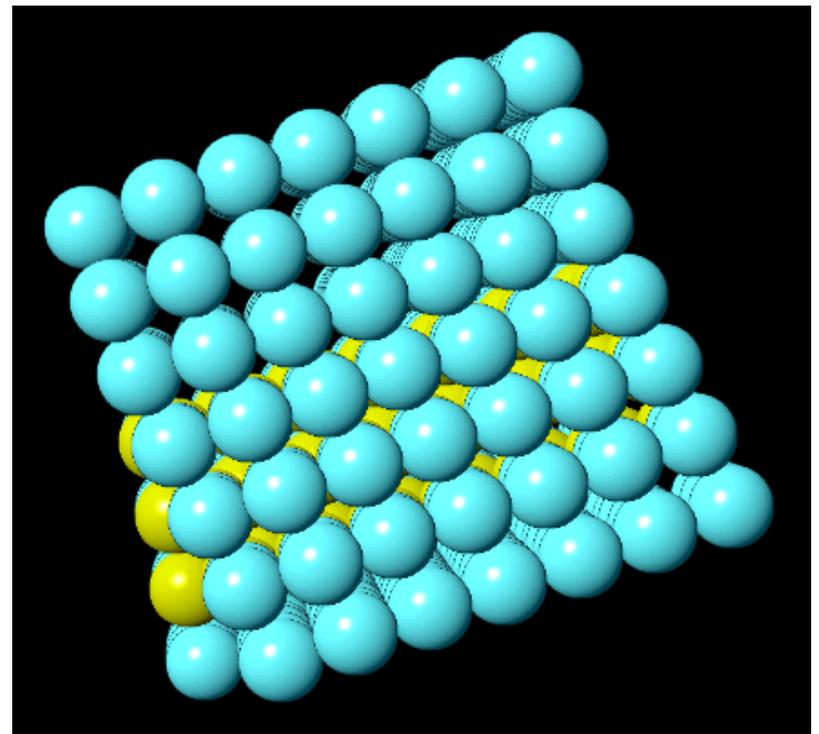
Adapted from Fig. 4.4, *Callister & Rethwisch 8e*.

VMSE: Screw Dislocation

- In VMSE:
 - a region of crystal containing a dislocation can be rotated in 3D
 - dislocation motion may be animated



Front View



Top View

VMSE Screen Shots



Imperfections in Solids

Dislocations are visible in electron micrographs

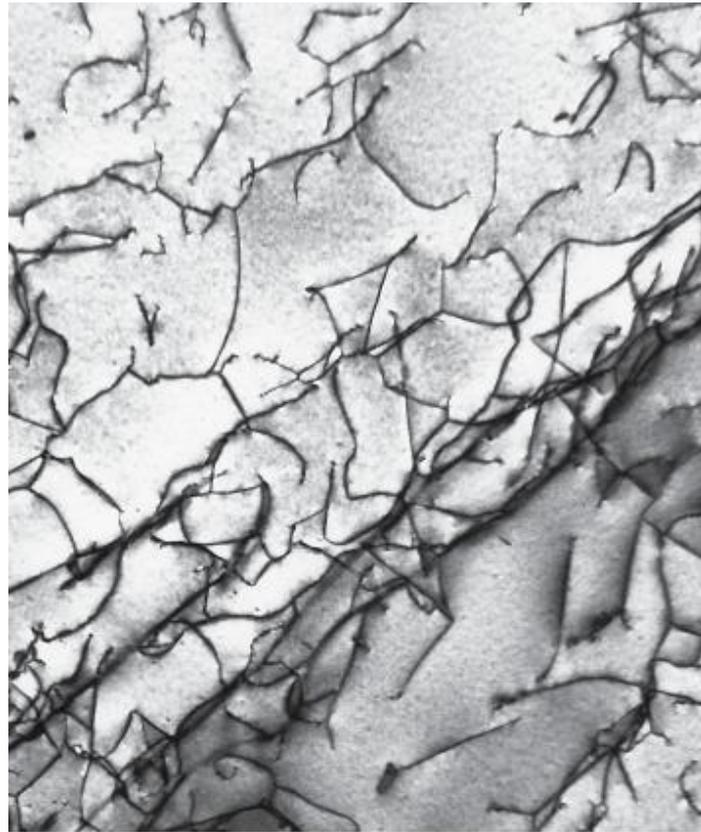


Fig. 4.6, *Callister & Rethwisch 8e.*

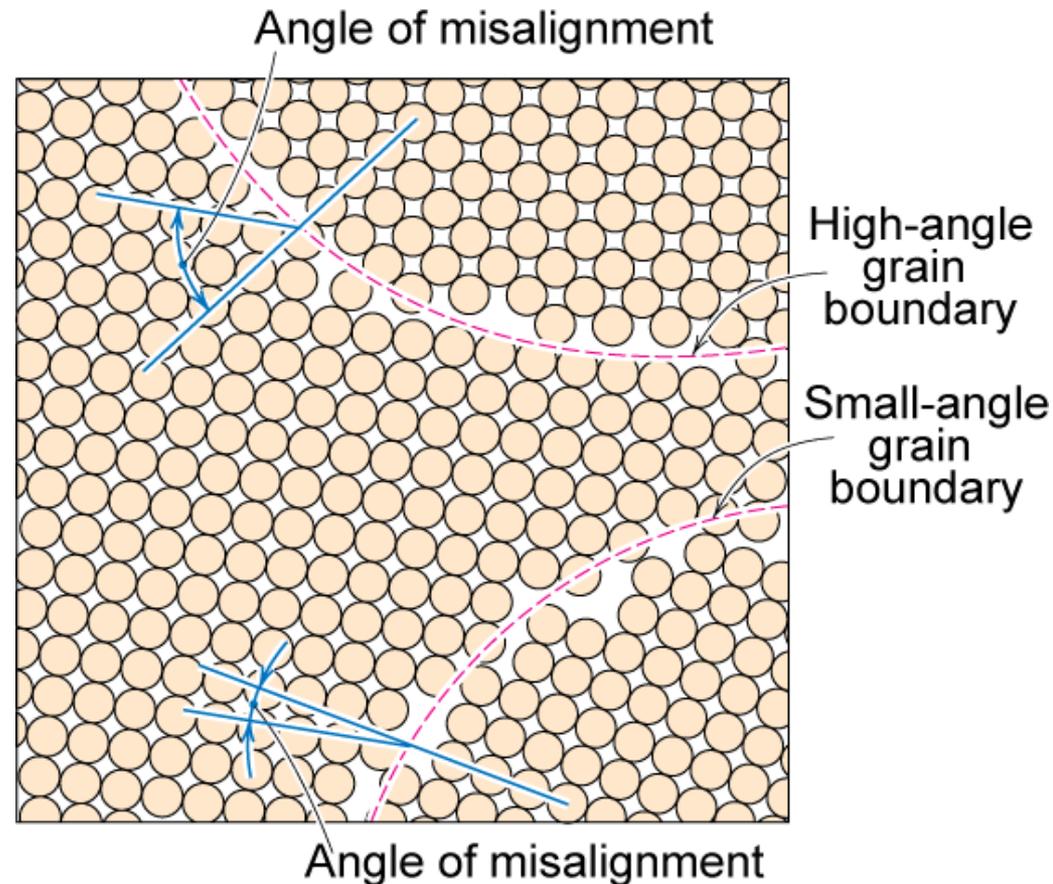
0.2 μm



Polycrystalline Materials

Grain Boundaries

- regions between crystals
- transition from lattice of one region to that of the other
- slightly disordered
- low density in grain boundaries
 - high mobility
 - high diffusivity
 - high chemical reactivity

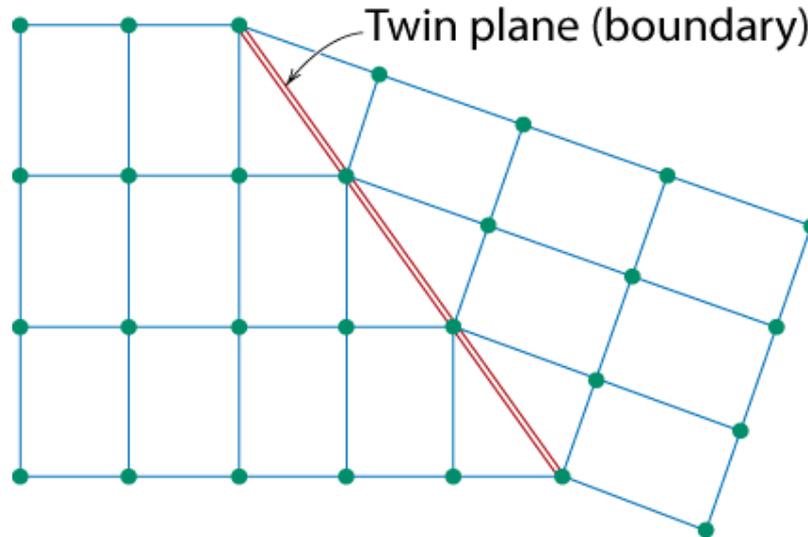


Adapted from Fig. 4.7,
Callister & Rethwisch 8e.



Planar Defects in Solids

- One case is a **twin boundary (plane)**
 - Essentially a reflection of atom positions across the **twin plane**.



Adapted from Fig. 4.9,
Callister & Rethwisch 8e.

- **Stacking faults**
 - For FCC metals an error in ABCABC packing sequence
 - Ex: ABCABABC

Catalysts and Surface Defects

- A **catalyst** increases the rate of a chemical reaction without being consumed
- Active sites on catalysts are normally surface defects

Single crystals of $(\text{Ce}_{0.5}\text{Zr}_{0.5})\text{O}_2$ used in an automotive catalytic converter

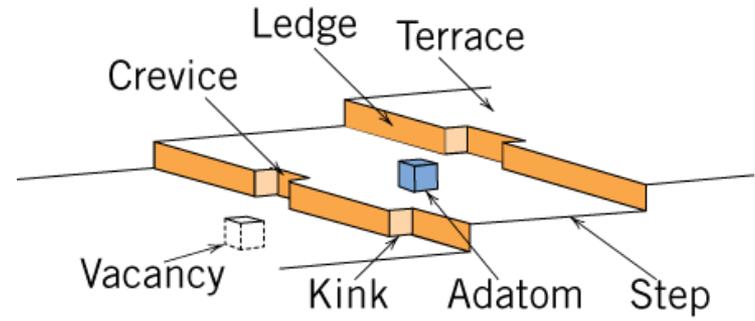


Fig. 4.10, Callister & Rethwisch 8e.

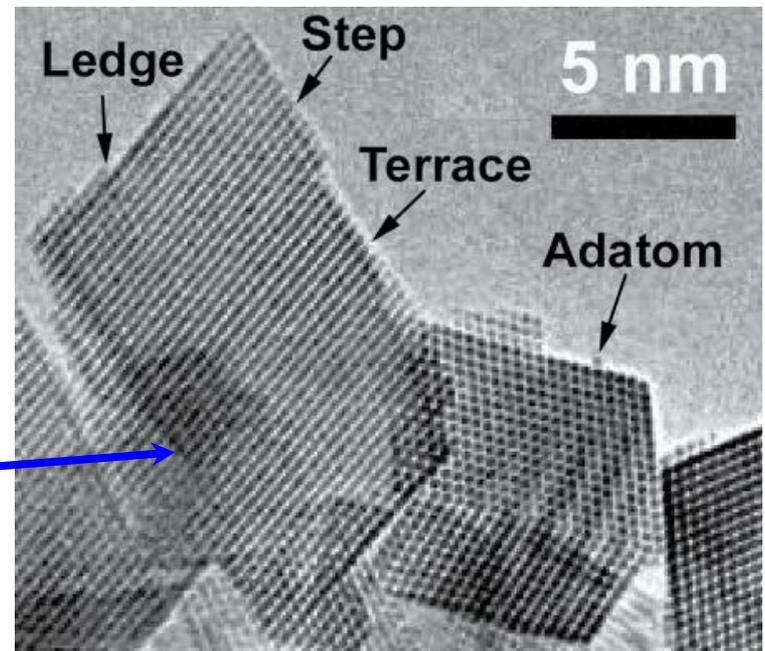


Fig. 4.11, Callister & Rethwisch 8e.



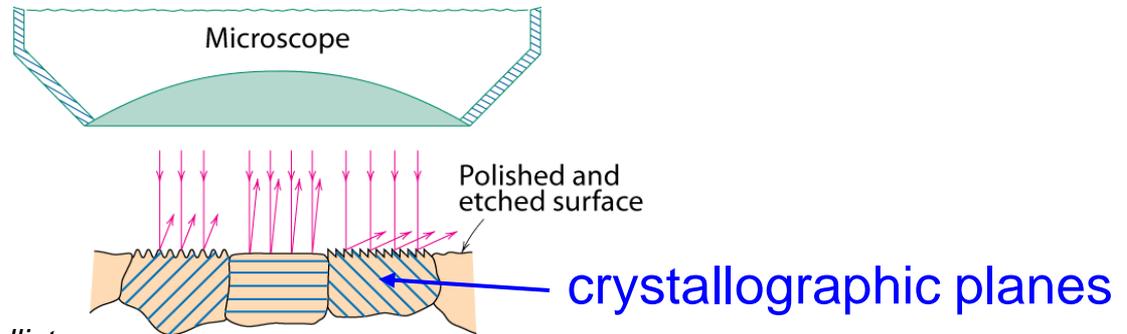
Microscopic Examination

- Crystallites (grains) and grain boundaries. Vary considerably in size. Can be quite large.
 - ex: Large single crystal of quartz or diamond or Si
 - ex: Aluminum light post or garbage can - see the individual grains
- Crystallites (grains) can be quite small (mm or less) – necessary to observe with a microscope.



Optical Microscopy

- Useful up to 2000X magnification.
- Polishing removes surface features (e.g., scratches)
- Etching changes reflectance, depending on crystal orientation.



Adapted from Fig. 4.13(b) and (c), *Callister & Rethwisch 8e*. (Fig. 4.13(c) is courtesy of J.E. Burke, General Electric Co.)



← 0.75mm →

Micrograph of brass (a Cu-Zn alloy)



Optical Microscopy

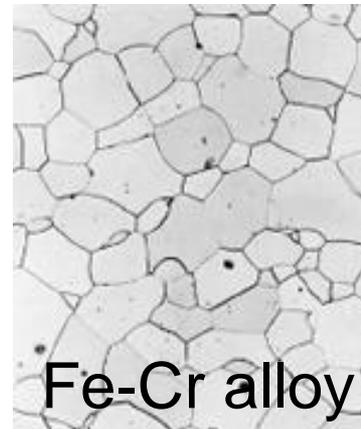
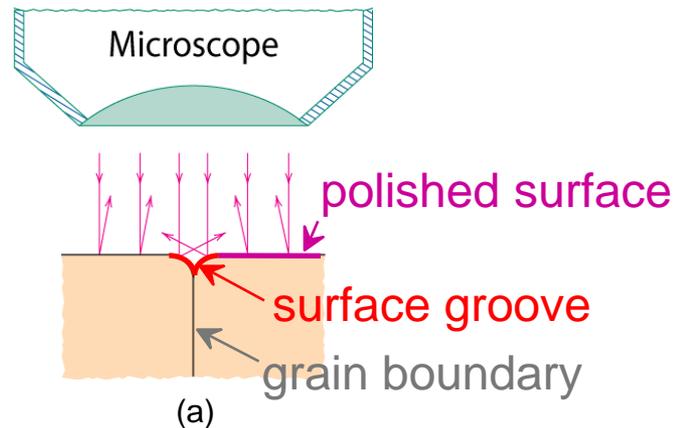
Grain boundaries...

- are imperfections,
- are more susceptible to etching,
- may be revealed as dark lines,
- change in crystal orientation across boundary.

ASTM grain size number

$$N = 2^{n-1}$$

number of grains/in²
at 100x
magnification



Adapted from Fig. 4.14(a) and (b), *Callister & Rethwisch 8e*. (Fig. 4.14(b) is courtesy of L.C. Smith and C. Brady, the National Bureau of Standards, Washington, DC [now the National Institute of Standards and Technology, Gaithersburg, MD].)



Optical Microscopy

- Polarized light
 - metallographic scopes often use polarized light to increase contrast
 - Also used for transparent samples such as polymers



Microscopy

Optical resolution ca. 10^{-7} m = 0.1 μ m = 100 nm

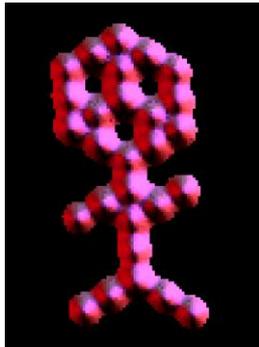
For higher resolution need higher frequency

- X-Rays? Difficult to focus.
- Electrons
 - wavelengths ca. 3 pm (0.003 nm)
 - (Magnification - 1,000,000X)
 - Atomic resolution possible
 - Electron beam focused by magnetic lenses.

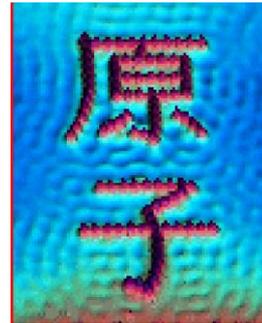


Scanning Tunneling Microscopy (STM)

- Atoms can be arranged and imaged!



Carbon monoxide molecules arranged on a platinum (111) surface.



Iron atoms arranged on a copper (111) surface. These Kanji characters represent the word "atom".

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Summary

- **Point**, **Line**, and **Area** defects exist in solids.
- The number and type of defects can be varied and controlled (e.g., T controls vacancy conc.)
- Defects affect material properties (e.g., grain boundaries control crystal slip).
- Defects may be desirable or undesirable (e.g., dislocations may be good or bad, depending on whether plastic deformation is desirable or not.)

